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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

FAIRCHILD
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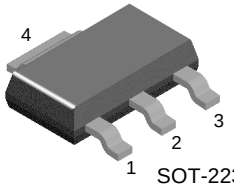
BSP50

NPN Darlington Transistor

- This device is designed for applications requiring extremly high current gain at collector currents to 500mA.
- Sourced from process 03.



SOT-223

1. Base 2. Collector 3. Emitter

Absolute Maximum Ratings* T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CER}	Collector-Emitter Voltage	45	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current - Continuous	800	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	- 55 ~ +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:
1) These ratings are based on a maximum junction temperature of 150°C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_a=25°C unless otherwise noted

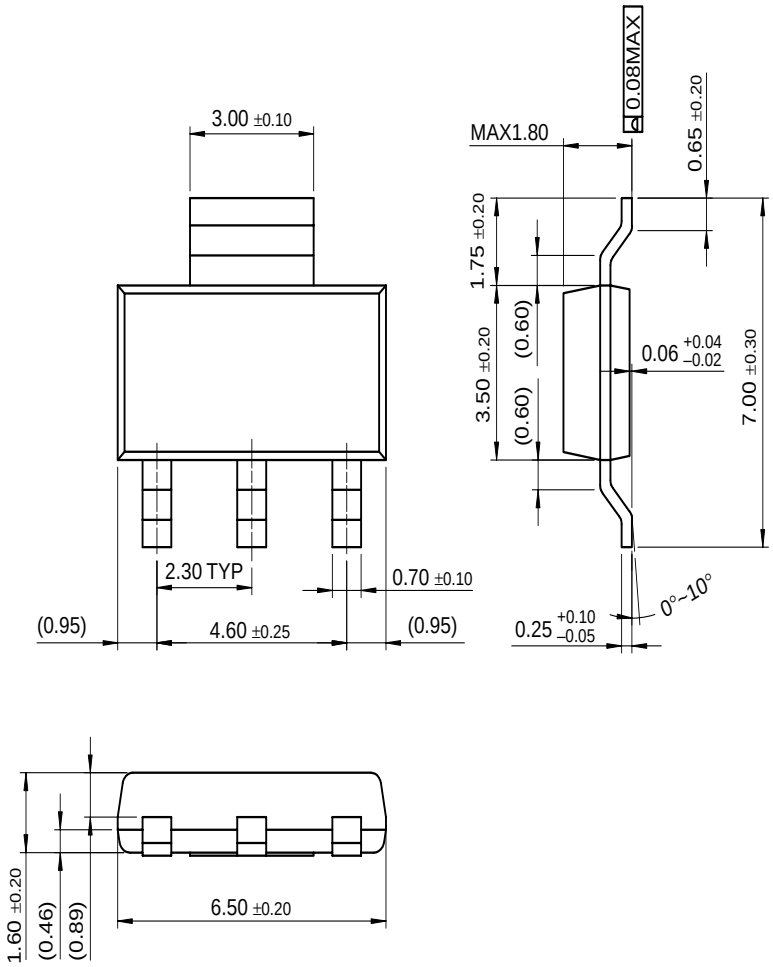
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = 100μA, I_E = 0	60			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 10μA, I_C = 0	5			V
I_{CES}	Collector Cutoff Current	V_{CE} = 45V, V_{BE} = 0			50	nA
I_{EBO}	Emitter Cutoff Current	V_{EB} = 4.0V, I_C = 0			50	nA
On Characteristics						
h_{FE}	DC Current Gain	I_C = 150mA, V_{CE} = 10V I_C = 500mA, V_{CE} = 10V	1000 2000			
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 500mA, I_B = 0.5mA			1.3	V
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = 500mA, I_B = 0.5mA			1.9	V

Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P_D	Total Device Dissipation Derate above 25°C	1000 8.0	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	125	°C/W

Package Dimensions

SOT-223



Dimensions in Millimeters

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CoolFET™	FRFET™	MicroFET™	QFET®	SuperSOT™-8
CROSSVOLT™	GlobalOptoisolator™	MicroPak™	QS™	SyncFET™
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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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